

# Lab 1: Power Management & Bootloading

ESE519/IPD519: Introduction to Embedded Systems  
University of Pennsylvania

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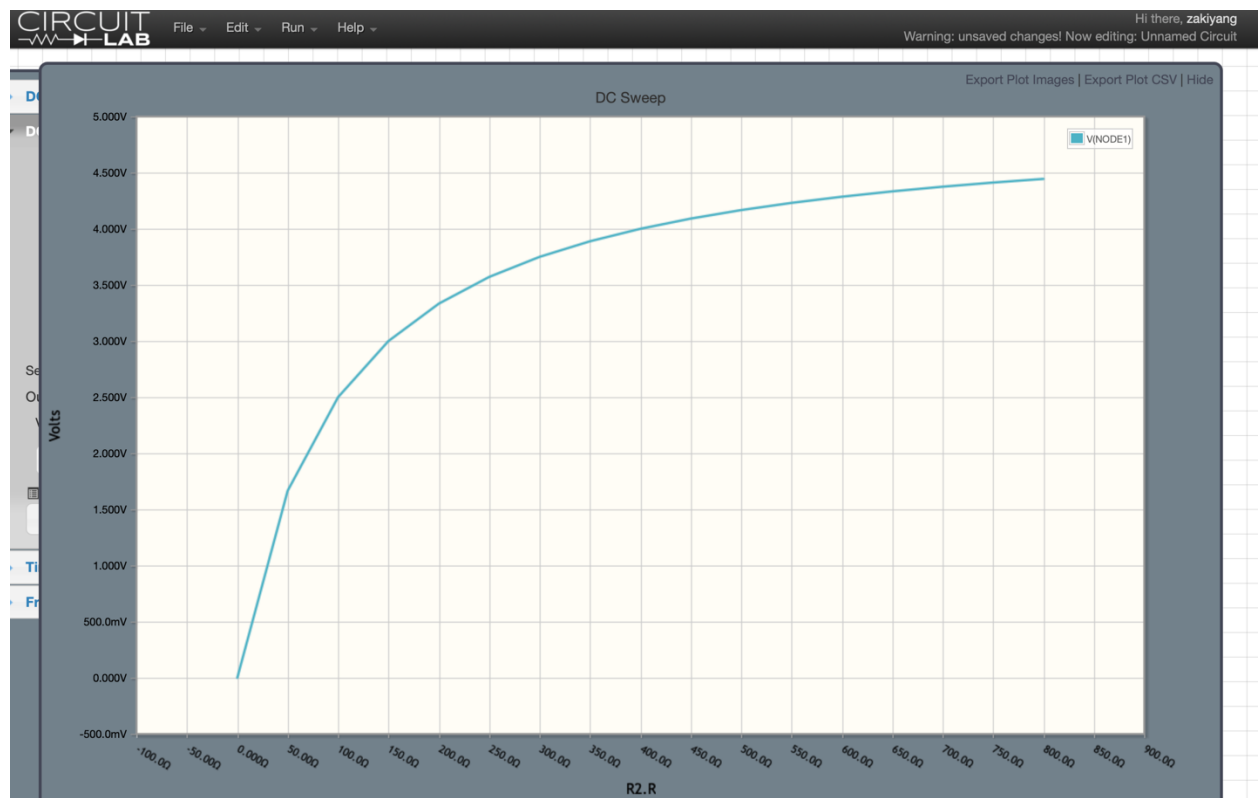
Pennkey:40094943

GitHub Repository: <https://github.com/Zakiyanggg/ESE519/>

## Par1: Voltage Regulator

Voltage divider

1. In the loop:  
 $V1 - I \cdot R1 - I \cdot R2 = 0$   
$$I = \frac{V1}{R1 + R2}$$
  
 $V_{node1} = V_{R2} = I \cdot R2 = (5V / (100\Omega + 100\Omega)) \cdot 100\Omega = 2.5V$
2. Change  $R2$  to  $850\Omega$   
 $V_{node1} = V_{R2} = I \cdot R2 = (5V / (100\Omega + 850\Omega)) \cdot 850\Omega = 4.47V$
- 3.



Yes, this graph matches the equation I derived in 1)

$$V_{\text{node1}} = V_{R2} = \frac{V_1}{R_1 + R_2} * R_2$$

4. 1) User would be able to get a lower voltage from a higher voltage source.  
2) A voltage divider circuit is handy and convenient to design and build, only resistors are involved.  
3) Can be used to measure a voltage source that too high to be directly measured.

### **Buck Converter**

5.

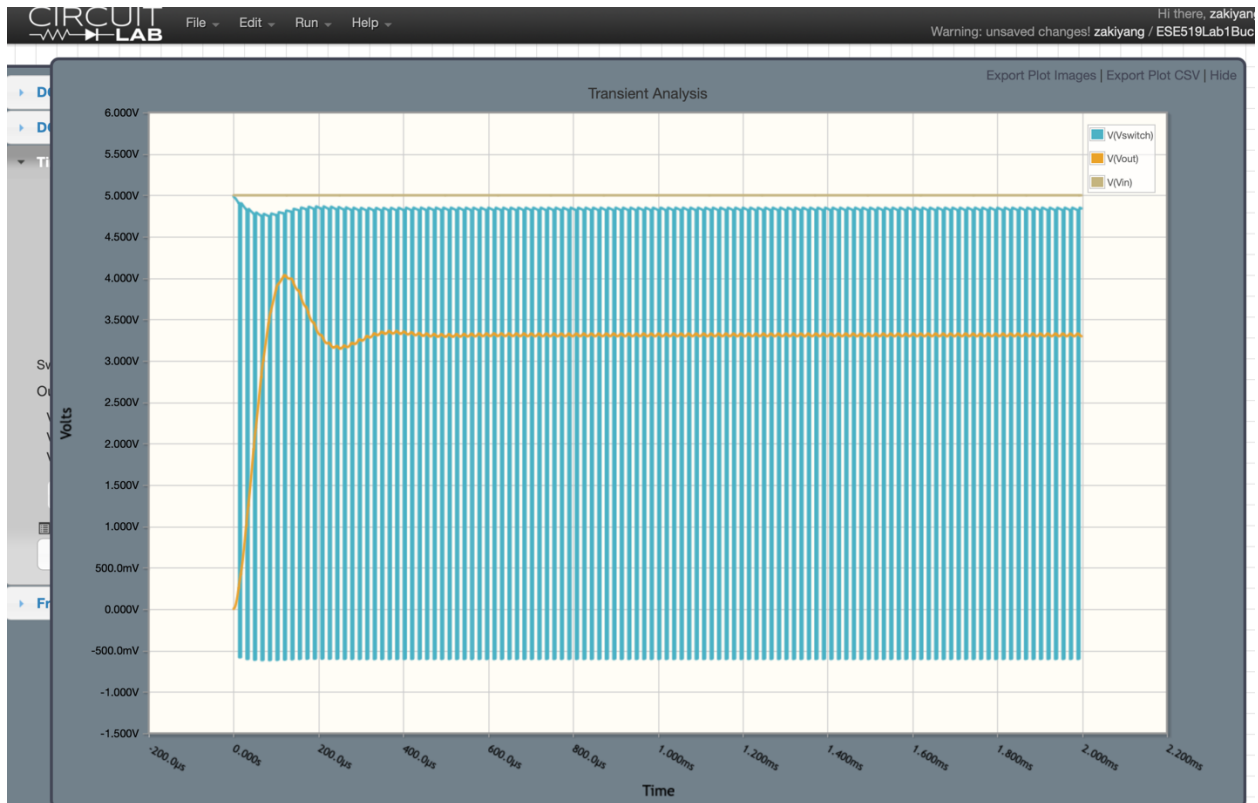
The duty cycle represents the fraction of one period in which a signal or system is active. It represents the low time of the pulse. The MOSFET is active when the pulse is low.

6.

In simulation, When  $V_{\text{out}} = 3.3\text{v}$  the duty cycle is 0.266.  $V_{\text{out}} = 2\text{v}$ , the duty cycle is 0.54

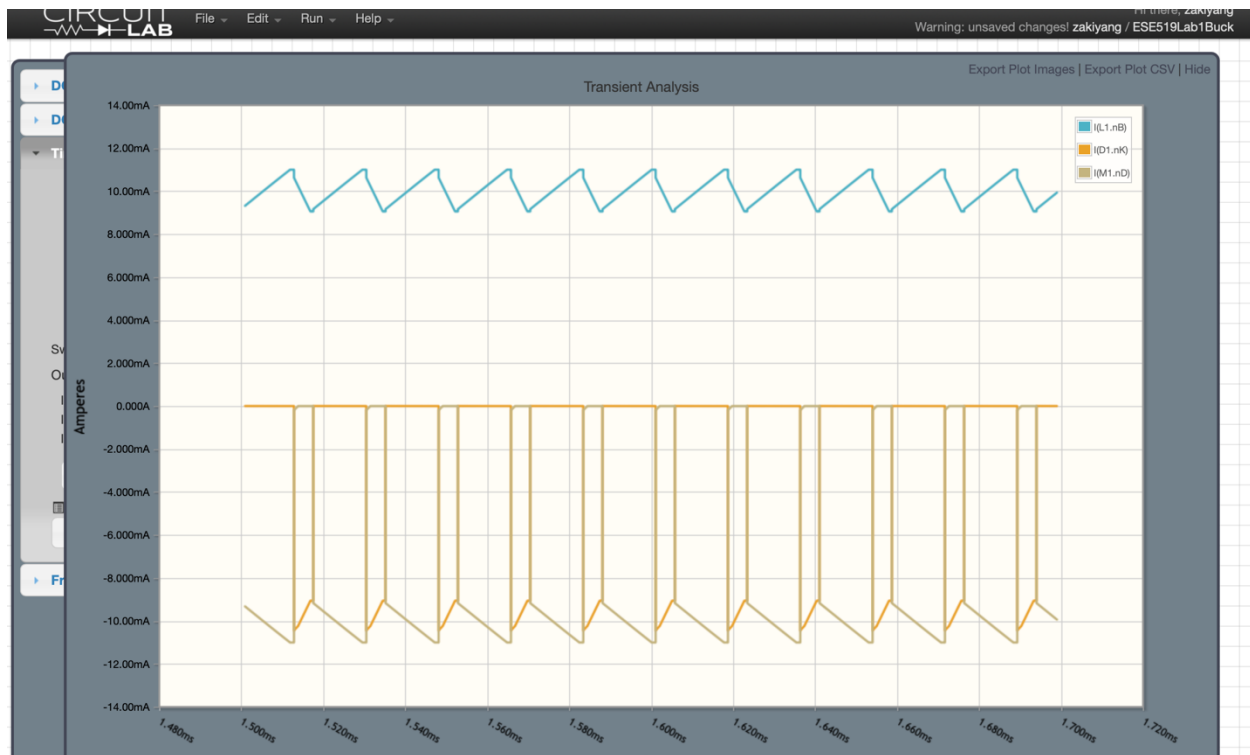
This does make sense since if the duty cycle decrease which will lead the on time of MOSFET longer. So, the output voltage would be higher since the RC circuit oscillates more. The components in the circuit such as the diode and the inductor would slightly affect the result.

7. Plot of  $V_{\text{out}} = 3.3\text{v}$



8.  
Because in the circuit there is a capacitor and an inductor. Both takes a while to charge and discharge then reach to a steady point.  
The reason why the steady state output is not a straight horizontal line is because the PWM signal oscillation between high and low state. So, the capacitor and inductor is continuously switching between charging and discharging. Thus, the Vout would oscillating in a certain range, and it can be count as steady output.

9.



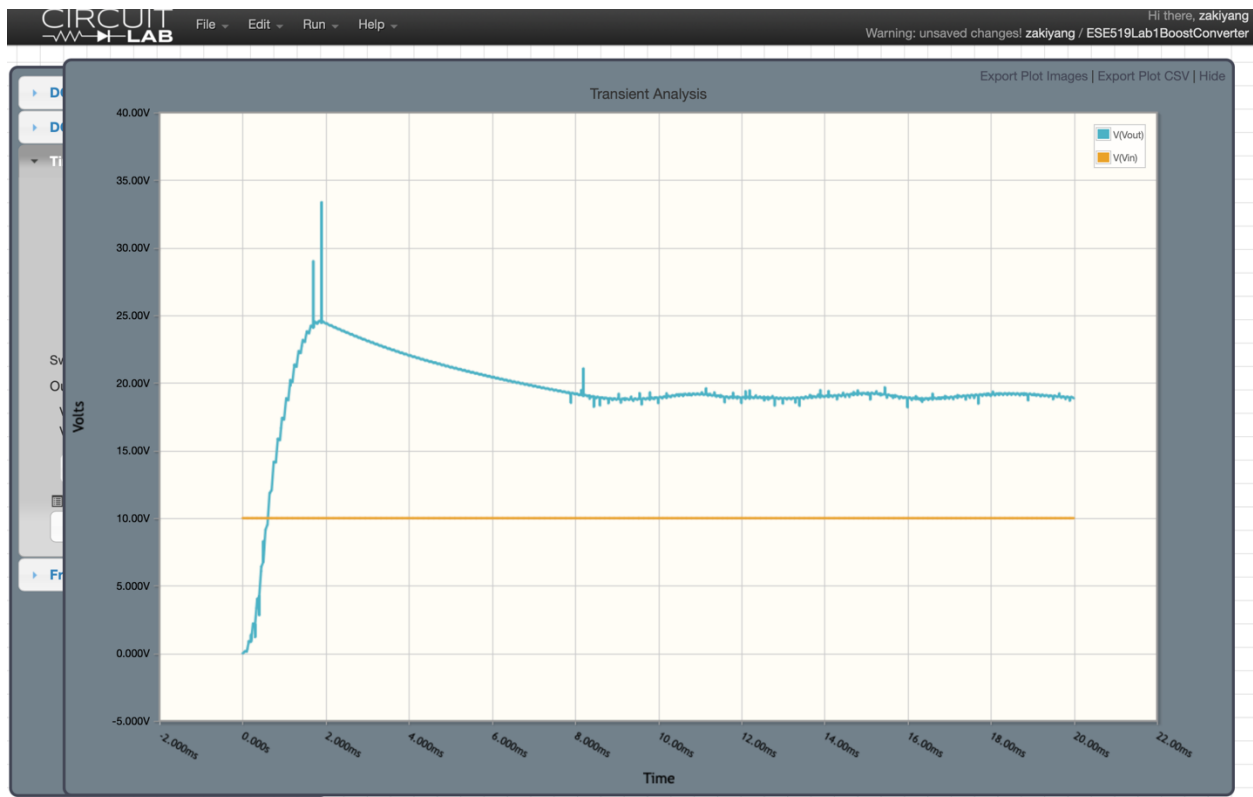
10.

KCL:  $I_{d1} + I_{l1} = I_{m1}$

The sum of the currents through one node is always zero. The graph matches this behavior.

## Boost Converter

11.

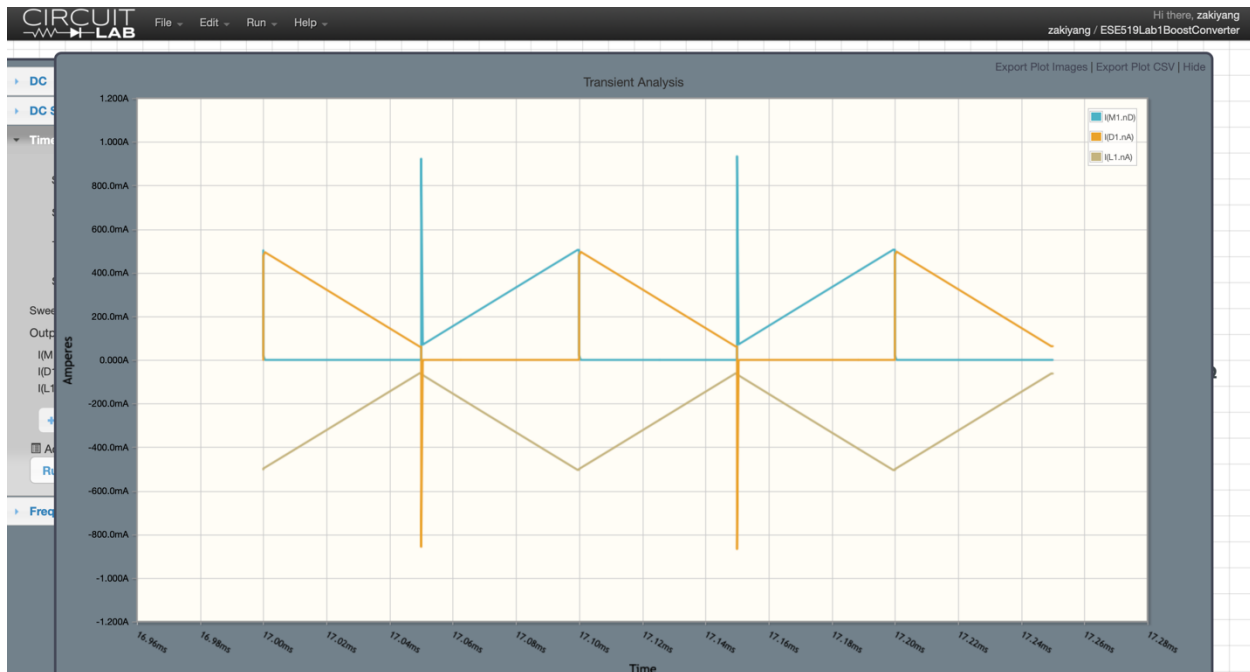


12.

Ideal output =  $V_{in}/(1-D)$ , as the duty cycle is 0.5 the output should be  $10/0.5 = 20\text{v}$ . As shown in the graph the steady state gives around 19v output voltage. The result is close to the ideal situation, so it is what I expected. The difference might be caused by the diode or other components in the circuit.

13.

For buck regulator the simulation plots for 2ms but for boost convertor it plots for 20ms. And the two clk frequencies are different. Also the output voltage of boost converter is much higher than buck regulator, this may cause more time to plot.



15.

According to KCL, the sum of the three current should always be zero. The graph matches the expectation.

## Part B: Aduino Power Management

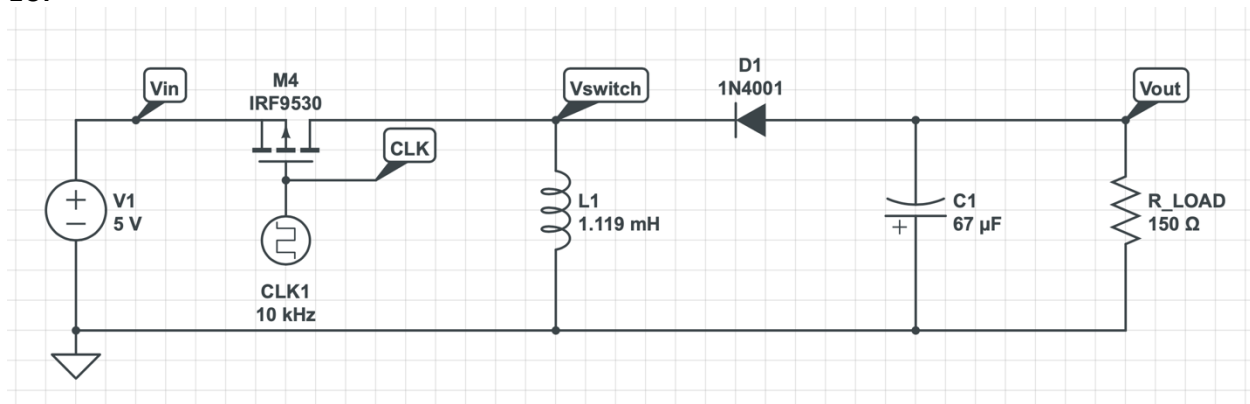
16.

Jack	USB	Power Source?	NODE1	NODE2	NODE3
0V	5V	USB	-928.8uV	4.999v	3.300v
10V	0V	Barrel Jack	5.001v	5.000v	3.300v
10V	5V	Barrel Jack	5.001v	5.000v	3.300v
3V	3V	USB	-928.8uV	4.999v	3.300v

17.

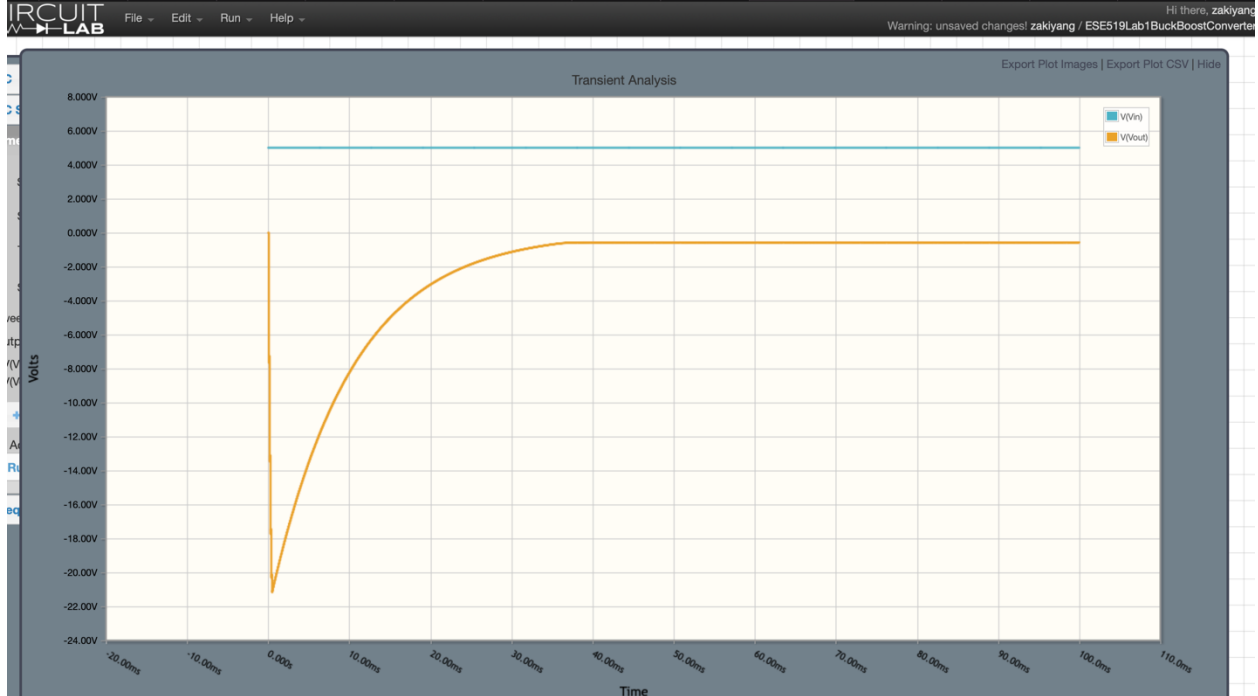
In this set up the system has a priority to use the USB as the voltage source. As the inverting input is 3.3v since there is a regulator. The barrel jack mush has a voltage input greater than  $3.3/1/2 = 6.6\text{v}$  to deactivate usb power input. So, if the divider is removed, the non-inverting input is always greater than 3.3v so the barrel jack will be the priority power input.

18.



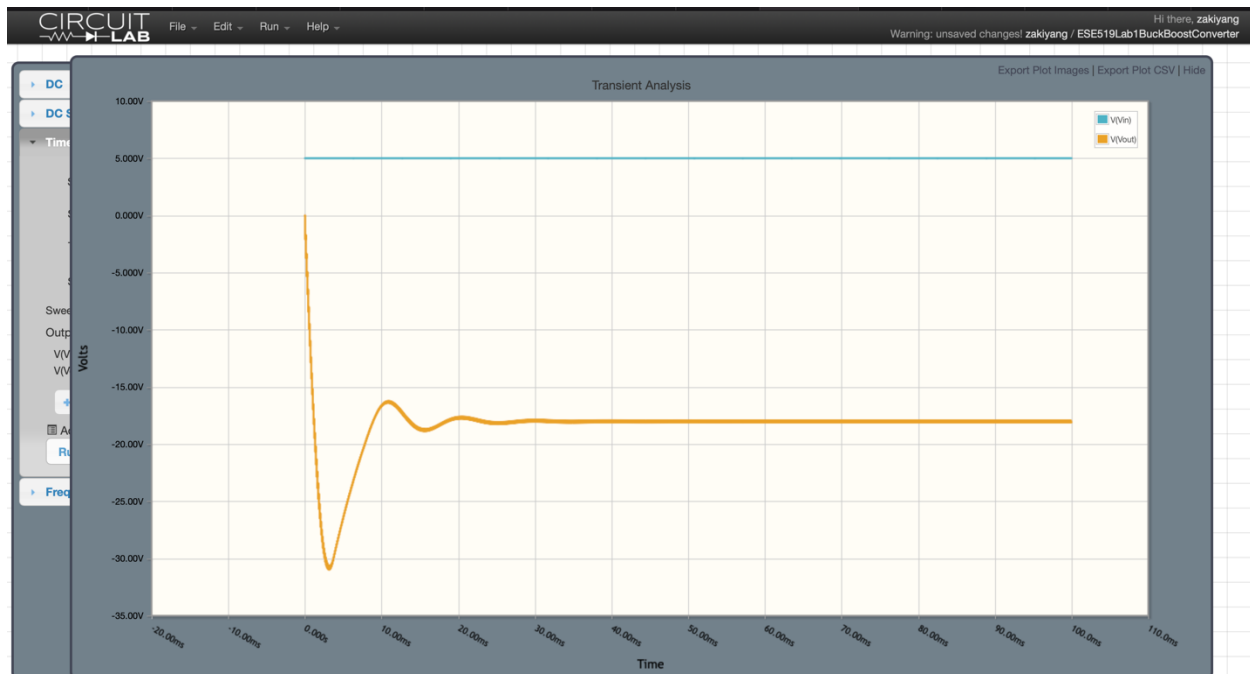
[https://www.circuitlab.com/circuit/kcf4hj77pe5y/ese519lab1buckboostconverter/#menu\\_file\\_link\\_and\\_share](https://www.circuitlab.com/circuit/kcf4hj77pe5y/ese519lab1buckboostconverter/#menu_file_link_and_share)

19.



0.2 Duty cycle (step Down)

20.



0.8 Duty cycle(step Up)

21.

BJT is a bipolar junction transistor and it's driven by current. MOSFET is field effect transistor that's driven by voltage. BJT may cause current leak and waste power. So for a system with smaller power consumption, BJT is a better choice. MOSFET is suitable for high power system so it usually has a higher cost than BJTs.